Providing improved output current limiting, the UDK/UDN/UDQ2549B and UDK/UDN/UDQ2549EB quad power drivers combine AND logic gates and high-current bipolar outputs with complete output protection. Each of the four outputs will sink 600 mA in the on state. The outputs have a minimum breakdown voltage (load dump) of 60 V and a sustaining voltage of 40 V. The inputs are compatible with TTL and 5 V CMOS logic systems.

Over-current protection for each channel has been designed into these devices and is activated at approximately 1 A. It protects each output from short circuits with supply voltages up to 25 V. When an output current trip point is reached, that output stage is driven linearly resulting in a reduced output current level. If an over-current or short circuit condition continues, the thermal limiting circuits will first sense the rise in junction temperature and then the rise in chip temperature, further decreasing the output current. Under worst-case conditions, the six devices in this family will tolerate short-circuits on all outputs, simultaneously.

These devices can be used to drive various loads including incandescent lamps (without warming or limiting resistors) or inductive loads such as relays, solenoids, or dc stepping motors.

The suffix 'B' devices are 16-pin power DIPs while the suffix 'EB' devices are 28-lead power PLCCs for surface-mount applications. Both packages are of batwing construction to provide for maximum package power dissipation.

# ABSOLUTE MAXIMUM RATINGS at $T_A = 25^{\circ}C$

**UDx2549B** 

GROUND

**GROUND** 

OUT₁

16 IN<sub>4</sub>

15 IN<sub>3</sub>

13

12

11

10 IN<sub>2</sub>

IN<sub>1</sub>

Dwa. PP-017-1

14 ENABLE

GROUND

GROUND

Output Voltage, V <sub>OUT</sub> <b>60 V</b>
Over-Current Protected Output Voltage,
V <sub>OUT</sub>
Output Current, I <sub>OUT</sub> 1.0 A*
Supply Voltage, V <sub>CC</sub> 7.0 V
Input Voltage, V <sub>IN</sub> or V <sub>EN</sub> <b>7.0 V</b>
Package Power Dissipation,
P <sub>D</sub> See Graph
Operating Temperature Range, T <sub>A</sub>
Prefix 'UDK'40°C to +125°C
Prefix 'UDN'20°C to +85°C
Prefix 'UDQ'40°C to +85°C
Storage Temperature Bange.

<sup>\*</sup>Outputs are peak current limited at approximately 1.0 A per driver. See Circuit Description and Applications for further information.

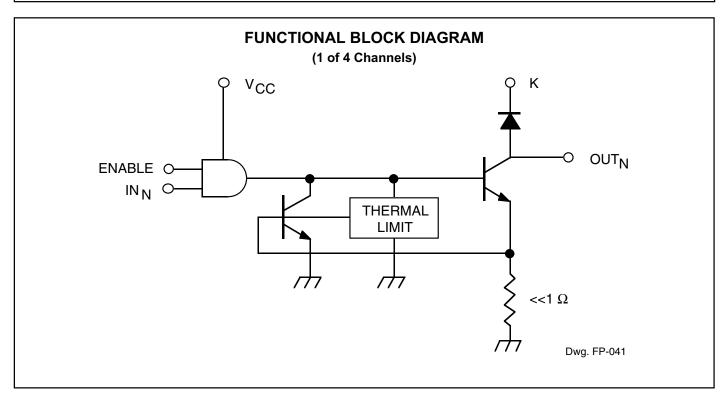
T<sub>S</sub>......--55°C to +150°C

#### **FEATURES**

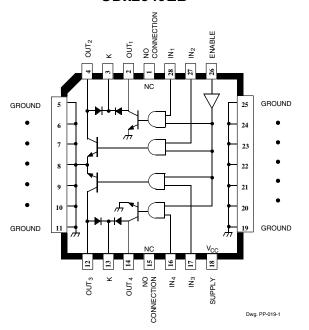
- 600 mA Output Current per Channel
- Independent Over-Current Protection for Each Driver
- Thermal Protection for Device and Each Driver
- Low Output-Saturation Voltage
- Integral Output Flyback Diodes
- TTL and 5 V CMOS Compatible Inputs
- Pin-Compatible With UDN2543B/EB

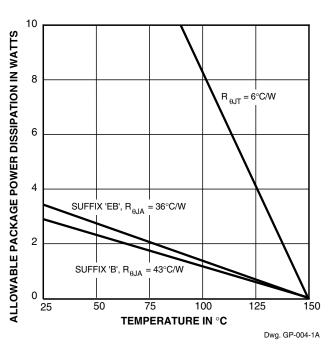
Always order by complete part number: a prefix to indicate operating temperature range + the basic four-digit part number + a suffix to indicate package style, e.g., **UDK2549EB**].





#### **UDx2549EB**







# ELECTRICAL CHARACTERISTICS at $T_A$ = +25°C (prefix 'UDN') or over operating temperature range (prefix 'UDK' or 'UDQ'), $V_{CC}$ = 4.75 V to 5.25 V

			Limits			
Characteristic	acteristic Symbol Test Conditions				Max.	Units
Output Leakage Current	I <sub>CEX</sub>	$V_{OUT} = 60 \text{ V}, V_{IN} = 0.8 \text{ V}, V_{EN} = 2.0 \text{ V}$	_	<1.0	100	μΑ
		$V_{OUT} = 60 \text{ V}, V_{IN} = 2.0 \text{ V}, V_{EN} = 0.8 \text{ V}$	_	<1.0	100	μΑ
Output Sustaining Voltage	V <sub>OUT(SUS)</sub>	I <sub>OUT</sub> = 100 mA, V <sub>IN</sub> = V <sub>EN</sub> = 0.8 V	40	_	_	V
Output Saturation Voltage	V <sub>OUT(SAT)</sub>	I <sub>OUT</sub> = 100 mA	_	_	200	mV
		I <sub>OUT</sub> = 400 mA	_	_	400	mV
		I <sub>OUT</sub> = 600 mA	_	_	600	mV
Over-Current Trip	I <sub>TRIP</sub>		_	1.0	_	Α
Input Voltage	Logic 1	V <sub>IN(1)</sub> or V <sub>EN(1)</sub>	2.0	_	_	V
	Logic 0	V <sub>IN(0)</sub> or V <sub>EN(0)</sub>	_	_	0.8	V
Input Current	Logic 1	$V_{IN(1)}$ or $V_{EN(1)} = 2.0 \text{ V}$	_	_	10	μΑ
	Logic 0	V <sub>IN(0)</sub> or V <sub>EN(0)</sub> = 0.8 V	_	_	-10	μΑ
Total Supply Current	I <sub>cc</sub>	$I_{OUT} = 600 \text{ mA}, V_{IN}^* = V_{EN} = 2.0 \text{ V}$	_	_	65	mA
		All Outputs OFF	_	_	15	mA
Clamp Diode Forward Voltage	V <sub>F</sub>	I <sub>F</sub> = 1.0 A	_	_	1.7	V
Clamp Diode Leakage Current	I <sub>R</sub>	$V_R = 60 \text{ V}, D_1 + D_2 \text{ or } D_3 + D_4$			50	μΑ
Thermal Limit	T <sub>J</sub>		_	165	_	°C

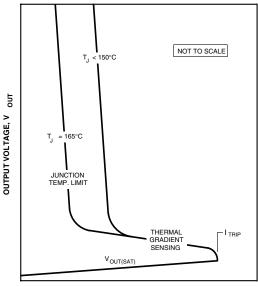
Typical Data is for design information only.

Negative current is defined as coming out of (sourcing) the specified terminal.

As used here, -100 is defined as greater than +10 (absolute magnitude convention) and the minimum is implicitly zero.

<sup>\*</sup> All inputs simultaneously, all other tests are performed with each input tested separately.

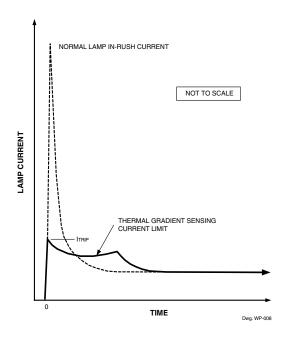
## TYPICAL OUTPUT CHARACTERISTIC



OUTPUT CURRENT, I

Dwg. GP-013

#### **TYPICAL OUTPUT BEHAVIOR**



#### **CIRCUIT DESCRIPTION AND APPLICATION**

#### **INCANDESCENT LAMP DRIVER**

High incandescent lamp turn-ON/in-rush currents can contribute to poor lamp reliability and destroy semiconductor lamp drivers. Warming or current-limiting resistors protect both driver and lamp but use significant power either when the lamp is OFF or when the lamp is ON, respectively. Lamps with steady-state current ratings up to 600 mA can be driven by these devices without the need for warming (parallel) or current-limiting (series) resistors.

When an incandescent lamp is initially turned ON, the cold filament is at minimum resistance and would normally allow a 10x to 12x in-rush current. With the these drivers, during turn-ON, the high in-rush current is sensed by the internal low-value sense resistor. Drive current to the output stage is then diverted by the shunting transistor, and the load current is momentarily limited to approximately 1.0 A. During this short transition period, the output current is reduced to a value dependent on supply voltage and filament resistance. During lamp warmup, the filament resistance increases to its maximum value, the output stage goes into saturation and applies maximum rated voltage to the lamp.

#### INDUCTIVE LOAD DRIVER

Bifilar (unipolar) stepper motors, relays, or solenoids can be driven directly. The internal flyback diodes prevent damage to the output transistors by suppressing the high-voltage spikes which occur when turning OFF an inductive load. For rapid current decay (fast turn-OFF speeds), the use of Zener diodes will raise the flyback voltage and improve performance. However, the peak voltage must not exceed the specified minimum sustaining voltage ( $V_{\text{SUPPLY}} + V_{\text{Z}} + V_{\text{F}} \leq V_{\text{OUT(SUS)}}$ ).

#### **FAULT CONDITIONS**

In the event of a shorted load, the load current will attempt to increase. As described above, the drive current to the affected output stage is reduced, causing the output stage to go linear, limiting the peak output current to approximately 1 A. As the power dissipation of that output stage increases, a thermal gradient sensing circuit will become operational, further decreasing the drive current to the affected output stage and reducing the output current to a value dependent on supply voltage and load resistance.

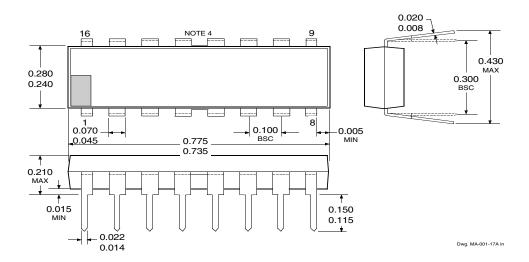
Continuous or multiple overload conditions causing the chip temperature to reach approximately 165°C will result in an additional reduction in output current to maintain a safe level.

If the fault condition is corrected, the output stage will return to its normal saturated condition.

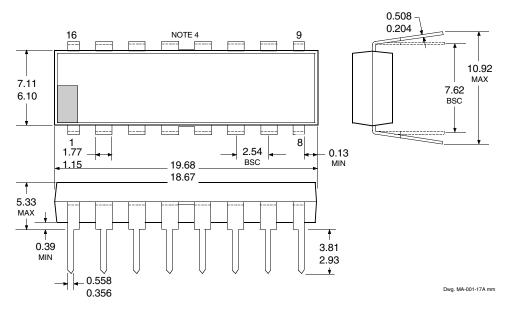


#### **UDN2549B** and **UDQ2549B**

Dimensions in Inches (controlling dimensions)



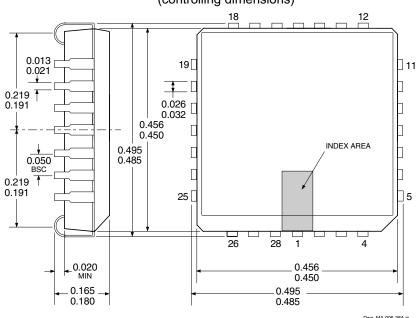
## Dimensions in Millimeters (for reference only)



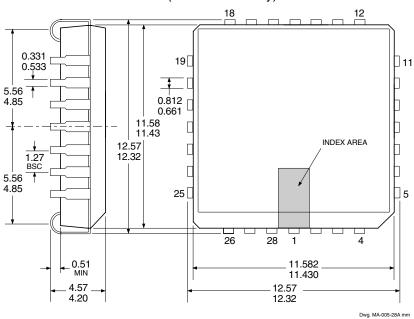
- NOTES: 1. Exact body and lead configuration at vendor's option within limits shown.
  - 2. Lead spacing tolerance is non-cumulative
  - 3. Lead thickness is measured at seating plane or below.
  - 4. Webbed lead frame. Leads 4, 5, 12, and 13 are internally one piece.

#### UDN2549EB and UDQ2549EB

Dimensions in Inches (controlling dimensions)



## Dimensions in Millimeters (for reference only)



- NOTES: 1. Exact body and lead configuration at vendor's option within limits shown.
  - 2. Lead spacing tolerance is non-cumulative
  - 3. Webbed lead frame. Leads 5 through 11 and 19 through 25 are internally one piece.



The products described here are manufactured under one or more U.S. patents or U.S. patents pending.

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## **POWER SINK DRIVERS**

#### IN ORDER OF 1) OUTPUT CURRENT, 2) OUTPUT VOLTAGE, 3) NUMBER OF DRIVERS

0.	itnut Patii	nae *	Features					
Output Ratings * -		Serial	Latched	Diode		Internal	_	
mA	V	#	Input	<b>Drivers</b>	Clamp	Outputs	Protection	Part Number <sup>†</sup>
75	17	8	X	X X	_	constant current	_	6275
100	17	16	X			constant current		6276
100	20 30	8		X	_	saturated	_	2595
	30 40	32 32	X X	â	_	- saturated	_	5833 5832
	50	8		ssable decod	ler/driver	DMOS	_	6B259
	50	8	_	X	_	DMOS	_	6B273
	50	8	Χ	X	-	DMOS	_	6B595
250	50	8	addre	ssable decod	ler/driver	DMOS	_	6259
	50	8	_ V	X	_	DMOS	_	6273
	50 135	8 7	X _	X	_ X	DMOS	_	6595 7003
300	45			all sensor/driv			X	5140
300	50	7	_ 11c	- -	er X X	_	_	2003
	50	8	_	_	Χ	_	_	2803
	50	8	_	_	Χ	saturated	_	2596
	60	4	_	_	X	saturated	X	2557
	95 95	7 8	_	_	X X X	<del>-</del> -	<u>-</u> -	2023 2823
350	50	4		X	X			5800
350	50 50	7	_	_	Ŷ	_	_	2004
	50	8	_	_	â	_	_	2804
	50	8	_	X	X X X	_	_	5801
	50	8	X	X	_	_	_	5821
	50	8	X	X	X	_	_	5841
	50 50	8 8	addre X	ssable decod	ier/ariver	DMOS DMOS	_	6A259 6A595
	80	8	X	X X X	_	DIVIOS	_	5822
	80	8	Â	â	Χ	_	_	5842
	95	7	_	_	X	_	_	2024
	95	8			X			2824
450	30	28		I- to 14-line d				6817
600	60	4 4	_	_	_ X	saturated	X X	2547 2549
700	60 60	4			X	saturated	X	2549 2543 and 2559
750	50	8			X	saturated saturated		2597
900	14	2	- 11	— - II / -   -   -			X	3625
900	26	2		all sensor/driv all sensor/driv		saturated saturated	X	3626
1000	46	4		er motor cont				7024 and 7029
1200	46	4		stepping cont				7042
1250	50	4		er motor trans			Х	5804
1200	50	4	– –	— — — — — — — — — — — — — — — — — — —	X	· –	_	2064 and 2068
1500	80	4	_	_	Х	_	_	2065 and 2069
1800	50	4	-	_	X	_	_	2544
	50	4	_	_	X	_	_	2540
3000	46	4	stepp	er motor cont	roller/drive	r MOS	_	7026
4000	46	4	micro	stepping cont				7044
4000	50 80	4 4	_	_	X X	<del>-</del> -	_	2878 2879
	00	4		_	^	_	-	2013

<sup>\*</sup> Current is maximum specified test condition, voltage is maximum rating. See specification for sustaining voltage limits or over-current protection voltage limits.

<sup>†</sup> Complete part number includes additional characters to indicate operating temperature range and package style.

